

Tuesday 4 February

11:10

Wide bandgap semiconductor detectors

Session \mid Location: FBK, Trento, Sala Stringa, Via Sommarive 18 38123 Povo di Trento ITALY \mid Convener: Thomas Bergauer

11:10-11:40

Silicon carbide detectors: from material advantage to new applications

Speaker

Dr Francesco La Via

11:40-12:00

Silicon Carbide Detector Development for HEP and Medical Applications

Speaker

Andreas Gsponer

12:00-12:20

Silicon Carbide Diodes at IMB-CNM: Advancing High-Precision Dosimetry for FLASH Radiotherapy

Speaker

Dr Celeste Fleta

12:20-12:35 A Wide Dynamic Range Beam Monitor for Ion Therapy Machines

Speaker

Simon Emanuel Waid

12:35-12:50

Observation of bias-dependent position flipping of the electric field maximumin in neutron irradiated SiC diodes

Speaker

Cristian Quintana San Emeterio

12:50